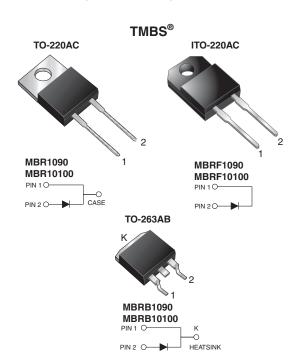
MBR10xxx-E3, MBRF10xxx-E3, MBRB10xxx-E3

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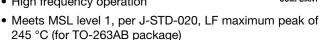
High Voltage Trench MOS Barrier Schottky Rectifier



PRIMARY CHARACTERISTICS				
I _{F(AV)}	10 A			
V _{RRM}	90 V, 100 V			
I _{FSM}	150 A			
V _F	0.65 V			
T _J max.	150 °C			
Package	TO-220AC, ITO-220AC, TO-263AB			
Diode variations	Single die			

FEATURES

- Trench MOS Schottky technology
- · Lower power losses, high efficiency
- Low forward voltage drop
- High forward surge capability
- High frequency operation



- Solder bath temperature 275 °C maximum, 10 s, per JESD 22-B106 (for TO-220AC and ITO-220AC package)
- · Material categorization: For definitions of compliance please see www.vishav.com/doc?99912

TYPICAL APPLICATIONS

For use in high frequency rectifier of switching mode power supplies, freewheeling diodes, DC/DC converters or polarity protection application.

MECHANICAL DATA

Case: TO-220AC, ITO-220AC, TO-263AB

Molding compound meets UL 94 V-0 flammability rating

Base P/N-E3 - RoHS-compliant, commercial grade

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 1A whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)				
PARAMETER	SYMBOL	MBR1090	MBR10100	UNIT
Maximum repetitive peak reverse voltage	V_{RRM}	90	100	V
Working peak reverse voltage	V_{RWM}	90	100	V
Maximum DC blocking voltage	V_{DC}	90	100	V
Maximum average forward rectified current at T _C = 133 °C	I _{F(AV)}	10		А
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load	I _{FSM}	150		А
Non-repetitive avalanche energy at T _J = 25 °C, L = 60 mH	E _{AS}	130		mJ
Peak repetitive reverse current at t_p = 2 μ s, 1 kHz, T_J = 38 °C \pm 2 °C per diode	I _{RRM}	0.5		А
Voltage rate of change (rated V _R)	dV/dt	10 000		V/µs
Isolation voltage (ITO-220AC only) from terminal to heatsink t = 1 min	V _{AC}	1500		V
Operating junction and storage temperature range	T _J , T _{STG}	-65 to +150		°C

MBR10xxx-E3, MBRF10xxx-E3, MBRB10xxx-E3

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ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)					
PARAMETER	TEST CONDITIONS		SYMBOL	MAX.	UNIT
	I _F = 10 A	T _C = 25 °C	V _F ⁽¹⁾	0.80	V
Maximum instantaneous forward voltage	I _F = 10 A	T _C = 125 °C		0.65	
	I _F = 20 A	T _C = 125 °C		0.75	
Maximum reverse current per at working peak reverse voltage		T _J = 25 °C	I _R ⁽²⁾	100	μΑ
		T _J = 125 °C		6.0	mA

Notes

(1) Pulse test: 300 µs pulse width, 1 % duty cycle

(2) Pulse test: Pulse width ≤ 40 ms

THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)					
PARAMETER	SYMBOL	MBR	MBRF	MBRB	UNIT
Typical thermal resistance	$R_{ hetaJA}$	60	-	60	°C/W
	$R_{ heta JC}$	2.0	3.5	2.0]

ORDERING INFORMATION (Example)						
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE	
TO-220AC	MBR10100CT-E3/4W	1.845	4W	50/tube	Tube	
ITO-220AC	MBRF10100CT-E3/4W	1.661	4W	50/tube	Tube	
TO-263AB	MBRB10100CT-E3/4W	1.384	4W	50/tube	Tube	
TO-263AB	MBRB10100CT-E3/8W	1.384	8W	800/reel	Tape and reel	

RATINGS AND CHARACTERISTICS CURVES ($T_A = 25$ °C unless otherwise noted)

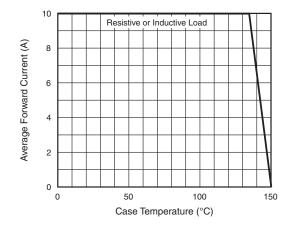


Fig. 1 - Forward Current Derating Curve

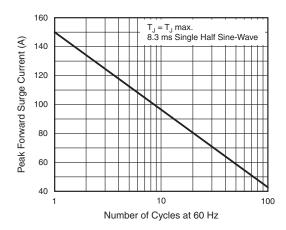


Fig. 2 - Maximum Non-Repetitive Peak Forward Surge Current



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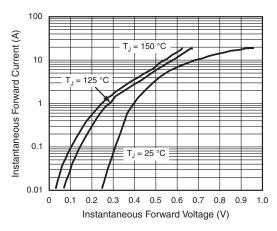


Fig. 3 - Typical Instantaneous Forward Characteristics

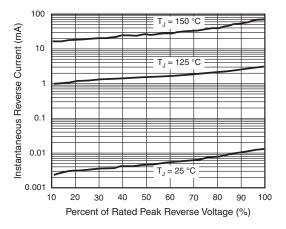


Fig. 4 - Typical Reverse Characteristics

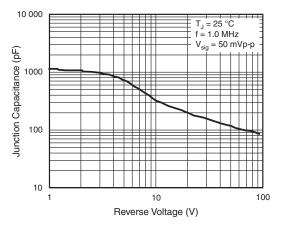


Fig. 5 - Typical Junction Capacitance

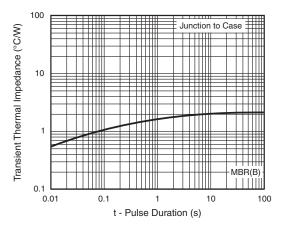


Fig. 6 - Typical Transient Thermal Impedance

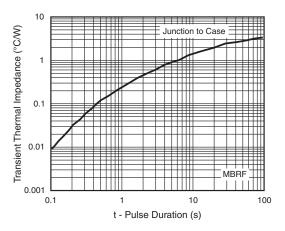


Fig. 7 - Typical Transient Thermal Impedance

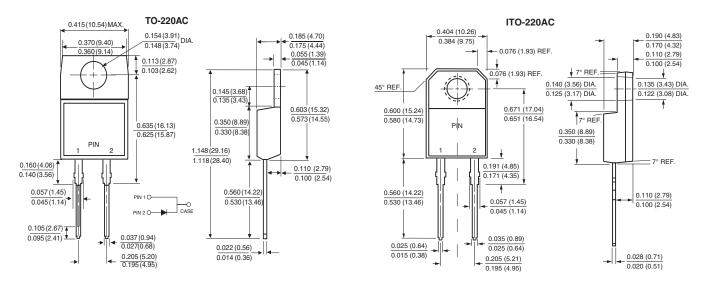


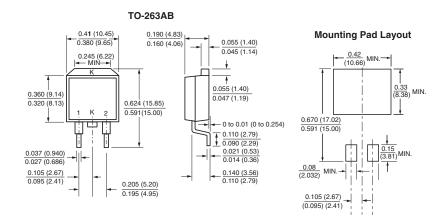
MBR10xxx-E3, MBRF10xxx-E3, MBRB10xxx-E3

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PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

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